74AUP1G74

Low-power D-type flip-flop with set and reset; positive-edge trigger

Rev. 11 — 3 July 2017

Product data sheet

1 General description

The 74AUP1G74 provides a low-power, low-voltage single positive-edge triggered D-type flip-flop with individual data (D), clock (CP), set ($\overline{S}D$) and reset ($\overline{R}D$) inputs and complementary Q and \overline{Q} outputs. The $\overline{S}D$ and $\overline{R}D$ are asynchronous active LOW inputs and operate independently of the clock input. Information on the data input is transferred to the Q output on the LOW-to-HIGH transition of the clock pulse. The D input must be stable one set-up time prior to the LOW-to-HIGH clock transition for predictable operation.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2 Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation
- · Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



3 Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AUP1G74DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74AUP1G74GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1
74AUP1G74GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm	SOT1089
74AUP1G74GM	-40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 × 1.6 × 0.5 mm	SOT902-2
74AUP1G74GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	SOT1116
74AUP1G74GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	SOT1203
74AUP1G74GX	-40 °C to +125 °C	X2SON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 × 0.8 × 0.35 mm	SOT1233

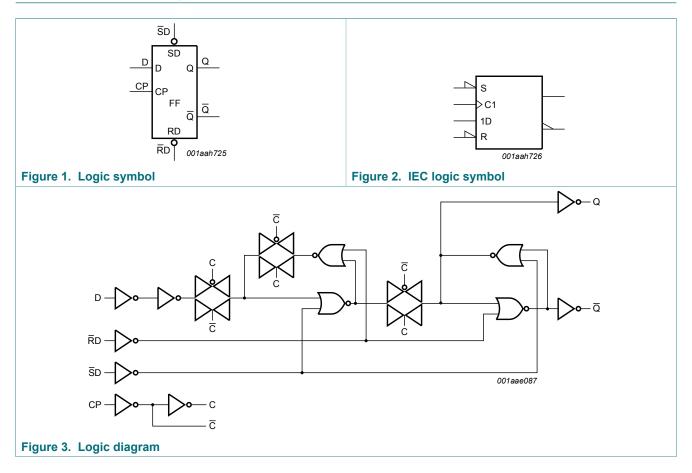
4 Marking

Table 2. Marking codes

Table 2. Walking codes					
Type number	Marking code ^[1]				
74AUP1G74DC	p74				
74AUP1G74GT	p74				
74AUP1G74GF	54				
74AUP1G74GM	p74				
74AUP1G74GN	54				
74AUP1G74GS	54				
74AUP1G74GX	54				

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

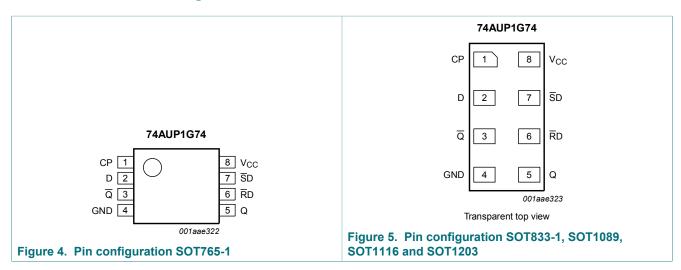
5 Functional diagram

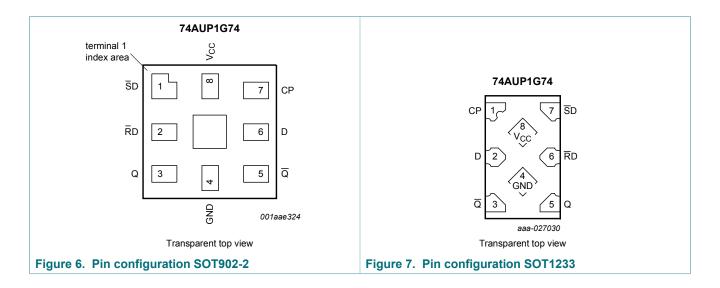


Low-power D-type flip-flop with set and reset; positive-edge trigger

6 Pinning information

6.1 Pinning





6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description	
	SOT765-1, SOT833-1, SOT1089, SOT1116, SOT1203 and SOT1233	SOT902-2	
СР	1	7	clock input
D	2	6	data input
Q	3	5	complement output
GND	4	4	ground (0 V)
Q	5	3	true output
RD	6	2	asynchronous reset input (active LOW)
SD	7	1	asynchronous set input (active LOW)
V_{CC}	8	8	supply voltage

7 Functional description

Table 4. Function table for asynchronous operation [1]

Input				Output		
SD	RD	СР	D	Q	Q	
L	Н	Х	X	Н	L	
Н	L	Х	X	L	Н	
L	L	Х	X	Н	Н	

^[1] H = HIGH voltage level;

Table 5. Function table for synchronous operation [1]

Input				Output	
SD	RD	СР	D	Q _{n+1}	Q _{n+1}
Н	Н	1	L	L	Н
Н	Н	↑	Н	Н	L

^[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

 \uparrow = LOW-to-HIGH CP transition;

 Q_{n+1} = state after the next LOW-to-HIGH CP transition.

L = LOW voltage level;

X = don't care.

Low-power D-type flip-flop with set and reset; positive-edge trigger

8 Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

		, ,		. •	•
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	[1]	-0.5	+4.6	V
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
I _O	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	+50	mA
I_{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ [2]	-	250	mW

The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 For VSSOP8 packages: above 110 °C the value of P_{tot} derates linearly with 8.0 mW/K.

9 Recommended operating conditions

Table 7. Operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	-	200	ns/V

^[2] For VSSOP8 packages: above 110 °C the value of P_{tot} derates linearly with 8.0 mW/K. For XSON8 and XQFN8 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K. For X2SON8 package: above 118 °C the value of P_{tot} derates linearly with 7.7 mW/K.

10 Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11		-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72		-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = 20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		$I_O = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.31	V
		I_{O} = 1.9 mA; V_{CC} = 1.65 V	-	-	0.31	V
		I_{O} = 2.3 mA; V_{CC} = 2.3 V	-	-	0.31	V
		I_{O} = 3.1 mA; V_{CC} = 2.3 V	-	-	0.44	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.31	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.44	V
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μΑ
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±0.2	μΑ
Δl _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.5	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Δl _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}; \text{ per pin}$ [1]	-	-	40	μA
Cı	input capacitance	V_{CC} = 0 V to 3.6 V; V_{I} = GND or V_{CC}	-	0.6	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.3	-	pF
T _{amb} = -40	°C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I_{O} = -4.0 mA; V_{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
I _I	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μΑ
I _{OFF}	power-off leakage current	V_I or V_O = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μΑ
Δl _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.9	μΑ

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}; \text{ per pin}$ [1]	-	-	50	μΑ
T _{amb} = -40	0 °C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.75 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.25 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	1.77	-	-	V
		I_{O} = -3.1 mA; V_{CC} = 2.3 V	1.67	-	-	V
		I_{O} = -2.7 mA; V_{CC} = 3.0 V	2.40	-	-	V
		I_{O} = -4.0 mA; V_{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$	-	-	±0.75	μA
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.75	μΑ
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	1.4	μΑ
Δl _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}; \text{ per pin}$ [1]	-	-	75	μΑ

^[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

AUP1G74 All information provided in this document is subject to legal disclaimers.

© Nexperia B.V. 2017. All rights reserved.

11 Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 10.

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	Tai	_{mb} = -40 °	°C to +	125 °C	Unit
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Min	Max (125 °C)	
$C_L = 5 pF$				'						
t _{pd}	propagation delay	CP to Q, \overline{Q} ; see Figure 8. [2]								
		V _{CC} = 0.8 V	-	25.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.9	6.7	14.0	2.6	14.2	2.6	14.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.4	4.5	7.6	2.3	8.3	2.3	8.6	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.5	5.7	1.7	6.5	1.7	6.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	2.6	3.8	1.4	4.4	1.4	4.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.5	2.2	3.1	1.2	3.4	1.2	3.7	ns
		\overline{SD} to Q, \overline{Q} ; see Figure 9. [2]								
		V _{CC} = 0.8 V	-	19.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.7	5.6	11.0	2.5	11.4	2.5	11.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.4	4.0	6.3	2.2	6.9	2.2	7.3	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.3	4.9	1.7	5.6	1.7	5.9	ns
		V _{CC} = 2.3 V to 2.7 V	1.9	2.7	3.7	1.7	4.0	1.7	4.2	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	2.5	3.2	1.5	3.6	1.5	3.8	ns
		\overline{RD} to Q, \overline{Q} ; see <u>Figure 9</u> . [2]								
		V _{CC} = 0.8 V	-	19.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	5.5	11.0	2.5	11.3	2.5	11.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	3.9	6.3	2.2	6.8	2.2	7.3	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.2	5.0	1.8	5.6	1.8	5.9	ns
		V _{CC} = 2.3 V to 2.7 V	1.9	2.6	3.6	1.7	4.1	1.7	4.3	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	2.4	3.3	1.5	3.6	1.5	3.8	ns
f _{max}	maximum	CP; see Figure 8.								
	frequency	V _{CC} = 0.8 V	-	53	-	-	-	-	-	MHz
		V _{CC} = 1.1 V to 1.3 V	-	203	-	170	-	170	-	MHz
		V _{CC} = 1.4 V to 1.6 V	-	347	-	310	-	300	-	MHz
		V _{CC} = 1.65 V to 1.95 V	-	435	-	400	-	390	-	MHz
		V _{CC} = 2.3 V to 2.7 V	-	550	-	490	-	480	-	MHz
		V _{CC} = 3.0 V to 3.6 V	-	619	-	550	-	510	-	MHz

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	Tai	_{mb} = -40 °	°C to +	125 °C	Unit
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Min	Max (125 °C)	
C _L = 10 p	F			-	ı	1			-	
t _{pd}	propagation	CP to Q, \overline{Q} ; see Figure 8. [2]								
	delay	V _{CC} = 0.8 V	-	28.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.1	7.5	15.8	2.9	16.1	2.9	16.1	ns
		V _{CC} = 1.4 V to 1.6 V	2.7	5.1	8.7	2.4	9.4	2.4	9.8	ns
		V _{CC} = 1.65 V to 1.95 V	2.5	4.1	6.5	2.2	7.2	2.2	7.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.2	4.6	1.8	5.3	1.8	5.6	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	2.8	3.8	1.6	4.1	1.6	4.4	ns
		\overline{SD} to Q, \overline{Q} ; see <u>Figure 9</u> . [2]								
		V _{CC} = 0.8 V	-	23.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.9	6.5	12.9	2.8	13.3	2.8	13.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.7	4.6	7.5	2.3	7.9	2.3	8.3	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	3.9	5.6	2.3	6.3	2.3	6.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	3.2	4.4	2.0	4.8	2.0	5.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	3.0	3.9	1.9	4.2	1.9	4.4	ns
		\overline{RD} to Q, \overline{Q} ; see <u>Figure 9</u> . [2]								
		V _{CC} = 0.8 V	-	22.7	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	6.4	12.8	2.7	13.2	2.7	13.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.6	4.5	7.5	2.3	8.1	2.3	8.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.5	3.3	5.8	2.3	6.3	2.3	6.7	ns
		V _{CC} = 2.3 V to 2.7 V	2.2	3.2	4.4	2.0	4.9	2.0	5.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	2.9	4.0	1.9	4.3	1.9	4.5	ns
f _{max}	maximum	CP; see Figure 8.								
	frequency	V _{CC} = 0.8 V	-	52	-	-	-	-	-	MHz
		V _{CC} = 1.1 V to 1.3 V	-	192	-	150	-	150	-	MHz
		V _{CC} = 1.4 V to 1.6 V	-	324	-	280	-	230	-	MHz
		V _{CC} = 1.65 V to 1.95 V	-	421	-	310	-	250	-	MHz
		V _{CC} = 2.3 V to 2.7 V	-	486	-	370	-	360	-	MHz
		V _{CC} = 3.0 V to 3.6 V	-	550	-	410	-	360	-	MHz

Symbol	Parameter	Conditions	T _{amb} = 25 °C		T_{amb} = -40 °C to +125 °C				Unit	
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Min	Max (125 °C)	
C _L = 15 p	F				ı	1			1	
t _{pd}	propagation	CP to Q, \overline{Q} ; see Figure 8. [2]								
	delay	V _{CC} = 0.8 V	-	32.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.5	8.3	17.6	3.3	17.8	3.3	18.0	ns
		V _{CC} = 1.4 V to 1.6 V	3.2	5.6	9.5	2.8	10.5	2.8	11.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.7	4.6	7.2	2.5	8.1	2.5	8.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.4	3.6	5.2	2.2	5.8	2.2	6.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	3.2	4.4	2.0	4.9	2.0	5.2	ns
		\overline{SD} to Q, \overline{Q} ; see <u>Figure 9</u> . [2]								
		V _{CC} = 0.8 V	-	26.7	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.3	7.3	14.7	3.1	15.2	3.1	15.4	ns
		V _{CC} = 1.4 V to 1.6 V	3.2	5.2	8.3	2.9	9.0	2.9	9.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.8	4.3	6.4	2.5	7.1	2.5	7.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.8	3.7	5.1	2.2	5.5	2.2	5.8	ns
		V _{CC} = 3.0 V to 3.6 V	2.5	3.5	4.6	2.4	5.0	2.4	5.2	ns
		\overline{RD} to Q, \overline{Q} ; see <u>Figure 9</u> . [2]								
		V _{CC} = 0.8 V	-	26.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	7.2	14.5	3.1	15.0	3.1	15.2	ns
		V _{CC} = 1.4 V to 1.6 V	3.1	5.1	8.4	2.7	9.2	2.7	9.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.7	4.3	6.5	2.6	7.3	2.6	7.7	ns
		V _{CC} = 2.3 V to 2.7 V	2.6	3.6	5.0	2.4	5.5	2.4	5.8	ns
		V _{CC} = 3.0 V to 3.6 V	2.4	3.4	4.6	2.3	5.0	2.3	5.2	ns
f _{max}	maximum	CP; see Figure 8.								
	frequency	V _{CC} = 0.8 V	-	50	-	-	-	-	-	MHz
		V _{CC} = 1.1 V to 1.3 V	-	181	-	120	-	120	-	MHz
		V _{CC} = 1.4 V to 1.6 V	-	301	-	190	-	160	-	MHz
		V _{CC} = 1.65 V to 1.95 V	-	407	-	240	-	190	-	MHz
		V _{CC} = 2.3 V to 2.7 V	-	422	-	300	-	270	-	MHz
		V _{CC} = 3.0 V to 3.6 V	-	481	-	320	-	300	-	MHz

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	Tai	_{mb} = -40 °	°C to +	125 °C	Unit
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Min	Max (125 °C)	
$C_L = 30 p$	F									
t _{pd}	propagation	CP to Q, \overline{Q} ; see Figure 8. [2]								
	delay	V _{CC} = 0.8 V	-	42.7	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.2	10.6	22.5	4.0	23.0	4.0	23.3	ns
		V _{CC} = 1.4 V to 1.6 V	3.7	7.2	12.0	3.7	13.3	3.7	14.0	ns
		V _{CC} = 1.65 V to 1.95 V	3.5	5.8	9.2	3.4	10.4	3.4	11.0	ns
		V _{CC} = 2.3 V to 2.7 V	3.3	4.7	6.6	3.0	7.3	3.0	7.8	ns
		V _{CC} = 3.0 V to 3.6 V	3.0	4.3	5.8	2.8	6.8	2.8	7.3	ns
		\overline{SD} to Q, \overline{Q} ; see <u>Figure 9</u> . [2]								
		V _{CC} = 0.8 V	-	37.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.0	9.5	19.8	3.8	20.8	3.8	21.1	ns
		V _{CC} = 1.4 V to 1.6 V	3.8	6.7	10.9	3.7	12.0	3.7	12.7	ns
		V _{CC} = 1.65 V to 1.95 V	3.7	5.6	8.4	3.5	9.3	3.5	9.9	ns
		V _{CC} = 2.3 V to 2.7 V	3.7	4.8	6.6	3.2	7.2	3.2	7.6	ns
		V _{CC} = 3.0 V to 3.6 V	3.4	4.6	6.0	3.1	6.8	3.1	7.1	ns
		$\overline{R}D$ to Q, \overline{Q} ; see <u>Figure 9</u> . [2]								
		V _{CC} = 0.8 V	-	36.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.9	9.4	19.5	3.8	20.2	3.8	20.5	ns
		V _{CC} = 1.4 V to 1.6 V	3.6	6.6	10.9	3.7	12.0	3.7	12.6	ns
		V _{CC} = 1.65 V to 1.95 V	3.5	5.5	8.5	3.5	9.5	3.5	10.1	ns
		V _{CC} = 2.3 V to 2.7 V	3.5	4.7	6.5	3.2	7.1	3.2	7.6	ns
		V _{CC} = 3.0 V to 3.6 V	3.3	4.4	6.1	3.1	7.1	3.1	7.5	ns
f _{max}	maximum	CP; see Figure 8.								
	frequency	V _{CC} = 0.8 V	-	28	-	-	-	-	-	MHz
		V _{CC} = 1.1 V to 1.3 V	-	145	-	70	-	70	-	MHz
		V _{CC} = 1.4 V to 1.6 V	-	185	-	120	-	110	-	MHz
		V _{CC} = 1.65 V to 1.95 V	-	270	-	150	-	120	-	MHz
		V _{CC} = 2.3 V to 2.7 V	-	290	-	190	-	170	-	MHz
		V _{CC} = 3.0 V to 3.6 V	-	315	-	200	-	190	-	MHz

Low-power D-type flip-flop with set and reset; positive-edge trigger

Symbol	Parameter	Conditions	Ta	T _{amb} = 25 °C			T_{amb} = -40 °C to +125 °C			
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Min	Max (125 °C)	
C _L = 5 pF	, 10 pF, 15 pF	and 30 pF				·	·			
t _{su}	set-up time	D to CP HIGH; see Figure 8.								
		V _{CC} = 0.8 V	-	3.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	0.6	-	1.2	-	1.2	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	0.3	-	0.6	-	0.6	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.4	-	0.5	-	0.5	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.2	-	0.4	-	0.4	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.3	-	0.4	-	0.4	-	ns
		D to CP LOW; see Figure 8.								
		V _{CC} = 0.8 V	-	3.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	0.5	-	1.2	-	1.2	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	0.3	-	0.7	-	0.7	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.4	-	0.7	-	0.7	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.5	-	0.7	-	0.7	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.6	-	0.8	-	0.8	-	ns
t _h	hold time	D to CP; see Figure 8.								
		V _{CC} = 0.8 V	-	-1.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	-0.3	-	0.5	-	0.5	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	-0.2	-	0.2	-	0.2	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	-0.2	-	0.1	-	0.1	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	-0.2	-	0.1	-	0.1	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	-0.2	-	0.1	-	0.1	-	ns
t _{rec}	recovery	RD; see Figure 9								
	time	V _{CC} = 1.1 V to 1.3 V	-	-0.5	-	-0.9	-	-0.9	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	-0.2	-	-0.6	-	-0.6	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	-0.2	-	-0.4	-	-0.4	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	-0.1	-	-0.1	-	-0.1	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	-0.1	-	-0.1	-	-0.1	-	ns
		SD; see Figure 9.								
		V _{CC} = 1.1 V to 1.3 V	-	-0.5	-	-0.3	-	-0.3	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	-0.4	-	-0.1	-	-0.1	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	-0.3	-	0	-	0	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	-0.2	-	0.1	-	0.1	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	-0.1	-	0.1	-	0.1	-	ns

74AUP1G74

All information provided in this document is subject to legal disclaimers.

© Nexperia B.V. 2017. All rights reserved.

Low-power D-type flip-flop with set and reset; positive-edge trigger

Symbol	Parameter	Conditions	T _{amb} = 25 °C			T _{amb} = -40 °C to +125 °C				Unit
				Typ ^[1]	Max	Min	Max (85 °C)	Min	Max (125 °C)	
t _W	pulse width	CP HIGH or LOW; see Figure 8.								
		V _{CC} = 1.1 V to 1.3 V	-	2.1	-	2.7	-	2.7	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	1.1	-	1.5	-	1.5	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.9	-	1.6	-	1.6	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.6	-	1.7	-	1.7	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.6	-	1.9	-	1.9	-	ns
		SD or RD LOW; see Figure 9.								
		V _{CC} = 1.1 V to 1.3 V	-	4.2	-	11.3	-	11.5	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	2.3	-	6.2	-	6.4	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	1.8	-	4.8	-	5.0	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	1.2	-	3.3	-	3.5	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	1.1	-	2.6	-	2.8	-	ns
C _{PD}	power dissipation	f_i = 1 MHz; [3] V_I = GND to V_{CC}								
	capacitance	V _{CC} = 0.8 V	-	2.8	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.9	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.5	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	3.9	-	-	-	-	-	pF

All typical values are measured at nominal V_{CC} .

f_i = input frequency in MHz;

f_o = output frequency in MHz;

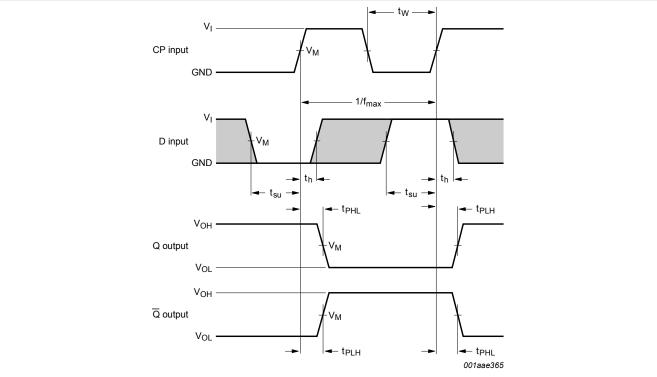
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$

All typical values are measured at the final t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

11.1 Waveforms and test circuit



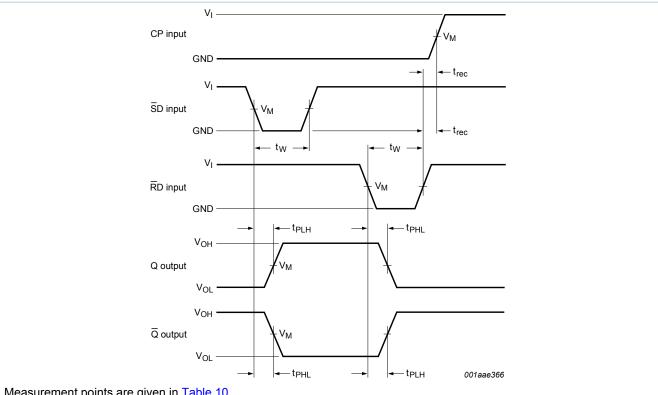
Measurement points are given in Table 10.

The shaded areas indicate when the input is permitted to change for predictable output performance.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 8. The clock input (CP) to output (\overline{Q} , \overline{Q}) propagation delays, the data input (D) to clock input (CP) set-up and hold times and the clock input (CP) pulse width and maximum frequency

Low-power D-type flip-flop with set and reset; positive-edge trigger



Measurement points are given in Table 10.

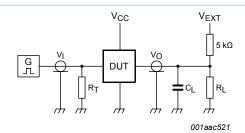
 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 9. The set input (\overline{SD}) and reset input (\overline{RD}) to output (\overline{Q} , \overline{Q}) propagation delays, the set input (\overline{SD}) and reset input (RD) pulse widths and the reset input (RD) to clock input (CP) recovery time

Table 10. Measurement points

Supply voltage	Output	Input					
V _{CC}	V _M	V _M	VI	$t_r = t_f$			
0.8 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns			

Low-power D-type flip-flop with set and reset; positive-edge trigger



Test data is given in Table 11.

Definitions for test circuit:

 R_I = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Zo of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

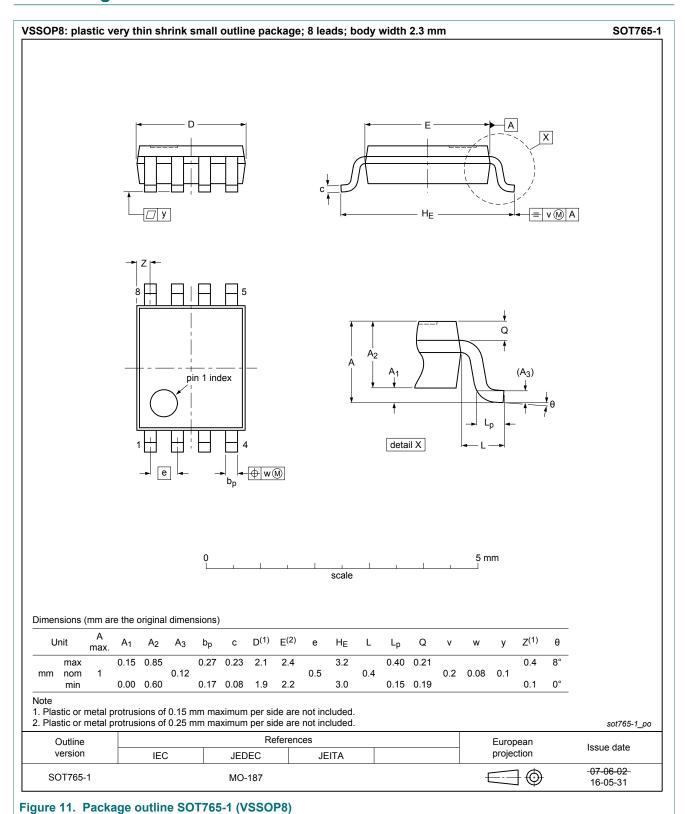
Figure 10. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load	V _{EXT}				
V _{CC}	CL	R _L ^[1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}	

[1] For measuring enable and disable times R_L = 5 k Ω For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

12 Package outline



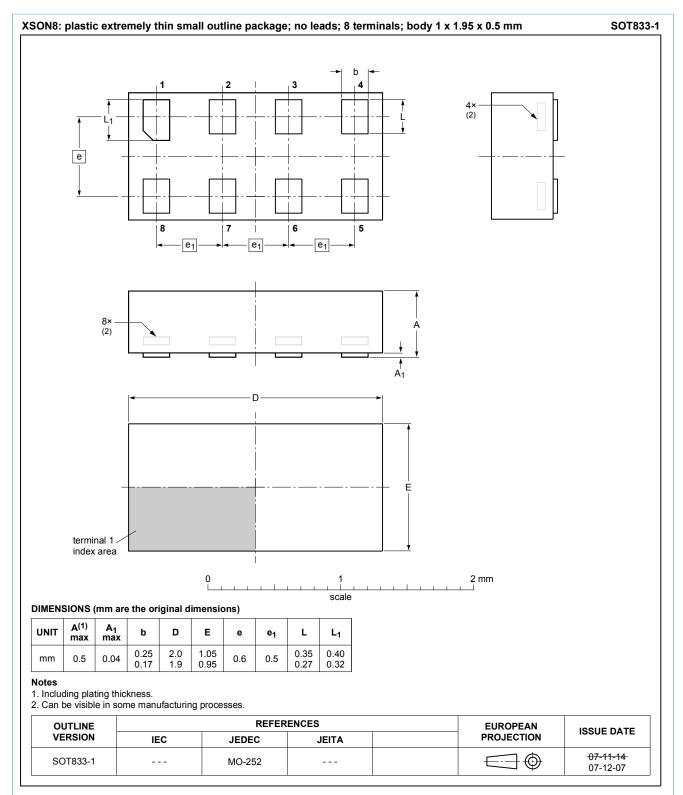
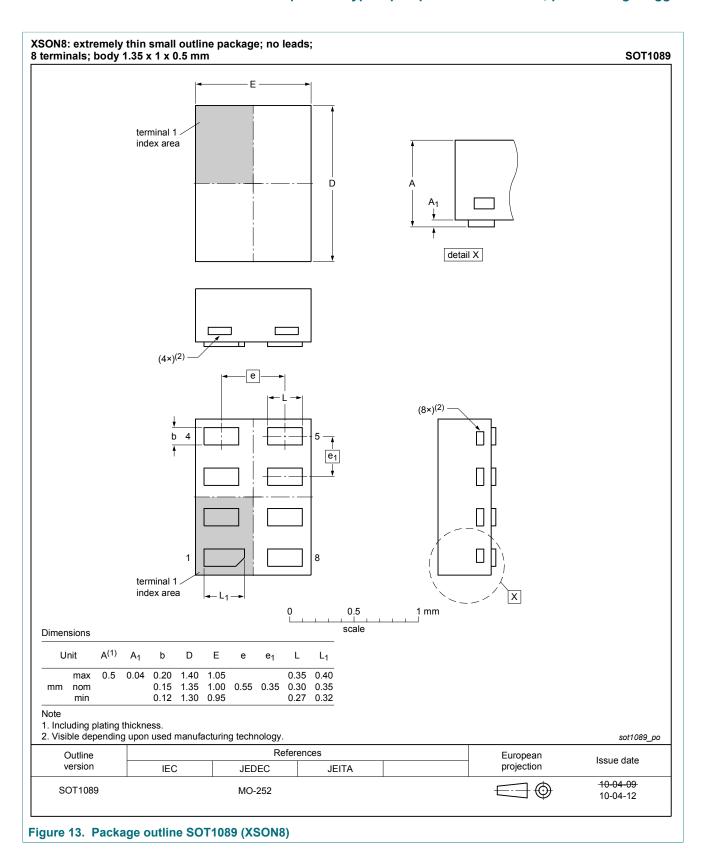
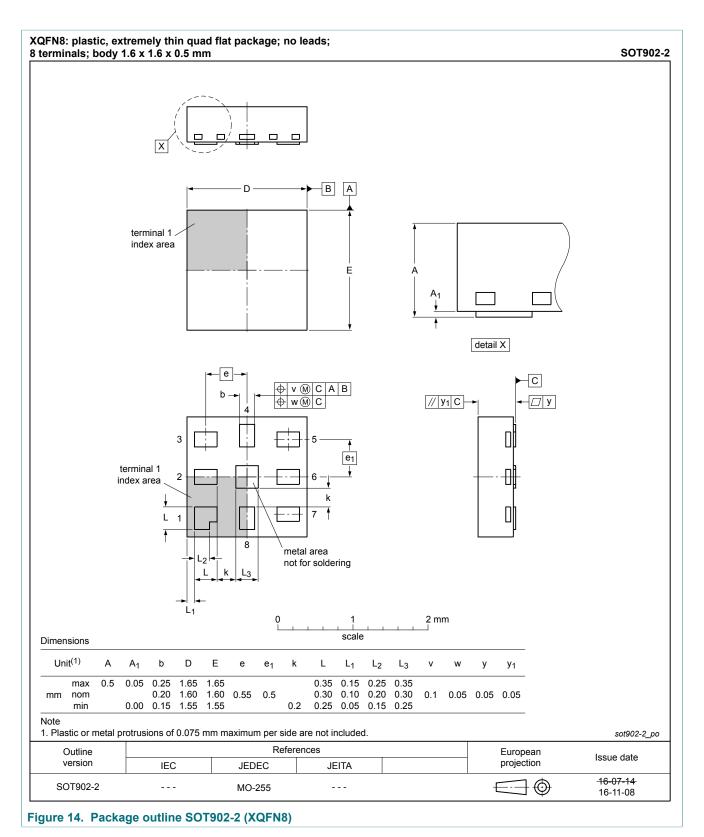


Figure 12. Package outline SOT833-1 (XSON8)





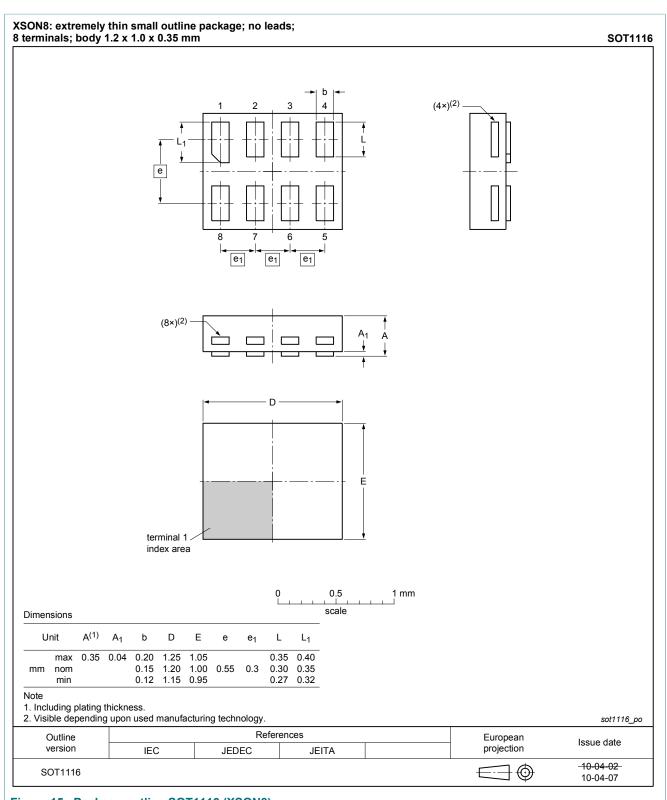
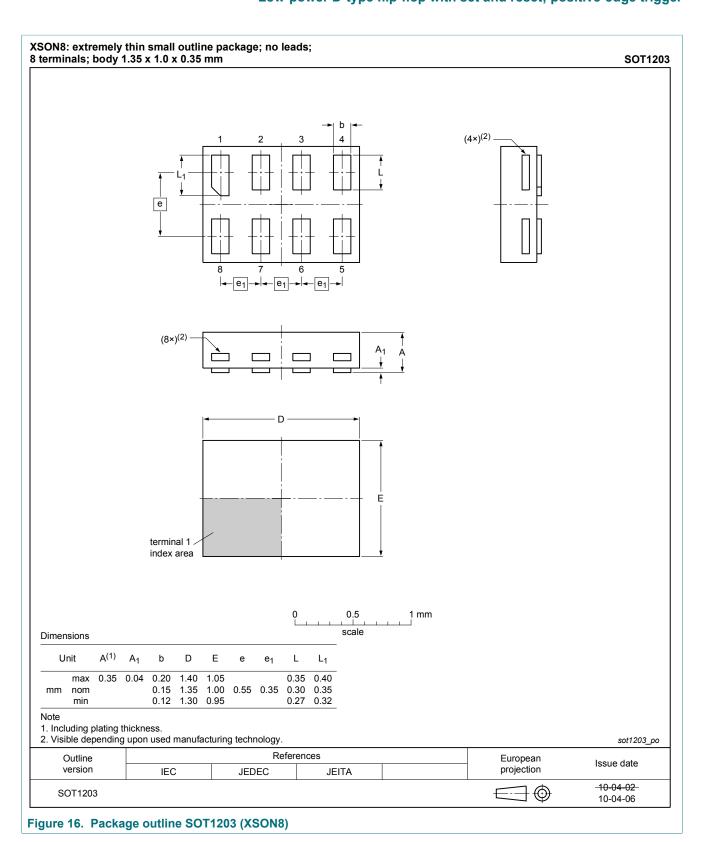
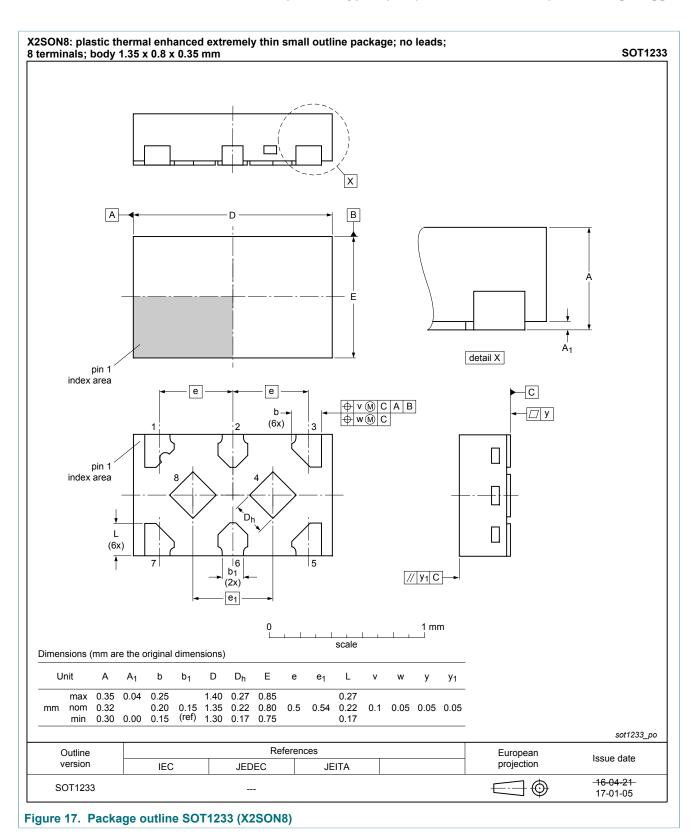


Figure 15. Package outline SOT1116 (XSON8)





Low-power D-type flip-flop with set and reset; positive-edge trigger

13 Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

14 Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G74 v.11	20170703	Product data sheet	-	74AUP1G74 v.10
Modifications:	Nexperia. • Legal texts hav • Figure 7 and Fi	nis data sheet has been re e been adapted to the ne gure 17 (drawings SOT12 4AUP1G74GD removed.	w company name w 233/X2SON8) update	
74AUP1G74 v.10	20161028	Product data sheet	-	74AUP1G74 v.9
Modifications:	 Added type nur 	mber 74AUP1G74GX (SC	T1233/X2SON8)	
74AUP1G74 v.9	20140106	Product data sheet	-	74AUP1G74 v.8
Modifications:	 Conditions for f 	max corrected (errata).		
74AUP1G74 v.8	20130123	Product data sheet	-	74AUP1G74 v.7
Modifications:	For type number	er 74AUP1G74GD XSON	8U has changed to	XSON8.
74AUP1G74 v.7	20120522	Product data sheet	-	74AUP1G74 v.6
74AUP1G74 v.6	20111128	Product data sheet	-	74AUP1G74 v.5
74AUP1G74 v.5	20100726	Product data sheet	-	74AUP1G74 v.4
74AUP1G74 v.4	20080603	Product data sheet	-	74AUP1G74 v.3
74AUP1G74 v.3	20080207	Product data sheet	-	74AUP1G74 v.2
74AUP1G74 v.2	20070515	Product data sheet	-	74AUP1G74 v.1
74AUP1G74 v.1	20060825	Product data sheet	-	-

15 Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- The term 'short data sheet' is explained in section "Definitions". [2] [3]
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

15.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

15.3 Disclaimers

Limited warranty and liability - Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia. In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory. Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification. Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products. Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

All information provided in this document is subject to legal disclaimers.

© Nexperia B.V. 2017. All rights reserved.

Low-power D-type flip-flop with set and reset; positive-edge trigger

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications. In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer

design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

15.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Contents

1	General description	1
2	Features and benefits	
3	Ordering information	2
4	Marking	
5	Functional diagram	
6	Pinning information	
6.1	Pinning	
6.2	Pin description	5
7	Functional description	
8	Limiting values	6
9	Recommended operating conditions	6
10	Static characteristics	
11	Dynamic characteristics	10
11.1	Waveforms and test circuit	16
12	Package outline	19
13	Abbreviations	
14	Revision history	26
15	Legal information	

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Nexperia:

74AUP1G74DC-Q100H

NXP: